# 21. Mosab: Mosab, Banisalman (7 publications)

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3. Kaseem M., Hussain T., Rehman Z.U., Banisalman M.J., Ko Y.G., Advantage of an in-situ reactive incorporation over direct particles incorporation of V2O5 for a competitive plasma electrolysis coating, Surface and Coatings Technology, 399, 126200, (2020-10-15). doi:10.1016/j.surfcoat.2020.126200 (cited 7 times).
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